

<b>Examiner-Initiated Interview Summary</b>		<b>Application No.</b> 10/598,934	<b>Applicant(s)</b> NAKAHATA ET AL.	
		<b>Examiner</b> SELIM AHMED	<b>Art Unit</b> 2826	

**All Participants:**

(1) SELIM AHMED.

(2) \_\_\_\_\_.

**Date of Interview:** 14 January 2010

**Type of Interview:**

☒ Telephonic  
☐ Video Conference  
☐ Personal (Copy given to: ☐ Applicant ☐ Applicant's representative)

**Exhibit Shown or Demonstrated:** ☐ Yes ☒ No  
 If Yes, provide a brief description: \_\_\_\_\_.

**Part I.**

Rejection(s) discussed:

Claims discussed:  
 12

Prior art documents discussed:

**Part II.**

SUBSTANCE OF INTERVIEW DESCRIBING THE GENERAL NATURE OF WHAT WAS DISCUSSED:  
*See Continuation Sheet*

**Part III.**

☒ It is not necessary for applicant to provide a separate record of the substance of the interview, since the interview directly resulted in the allowance of the application. The examiner will provide a written summary of the substance of the interview in the Notice of Allowability.

☐ It is not necessary for applicant to provide a separate record of the substance of the interview, since the interview did not result in resolution of all issues. A brief summary by the examiner appears in Part II above.

(Applicant/Applicant's Representative Signature – if appropriate)

Continuation of Substance of Interview including description of the general nature of what was discussed: An amendment to claim 12 was proposed by the Examiner to overcome the prior art and clearly stating the invention. One of the key features of the invention is "simultaneously growing at least two Group III nitride semiconductor crystal on the starting substrate" along with other elements that distinguishes the invention from prior art. Based on the conducted search results, the examiner believes that inserting "simultaneously" after 'a step of growing' in line 3 of claim 12 would result the application in condition for allowance. Such proposed amendment was accepted by applicants.